



P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BVDSS	Rds(on)	I _D T _A = +25°C
-30V	0.9Ω @ V _{GS} = -10V	-0.81 A
	1.7Ω @ V _{GS} = -4.5V	-0.58 A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Load Switch

Features and Benefits

- 0.6mm² Footprint—Thirteen Times Smaller than SOT23
- Low Gate Threshold Voltage
- Fast Switching Speed
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMP31D7LFBQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

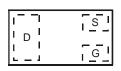
- Package: X1-DFN1006-3
- Package Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—NiPdAu over Copper Lead-Frame.
 Solderable per MIL-STD-202, Method 208
- Weight: 0.001 grams (Approximate)



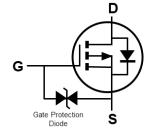
X1-DFN1006-3



Bottom View



Top View Internal Schematic



Equivalent Circuit

Ordering Information (Note 4)

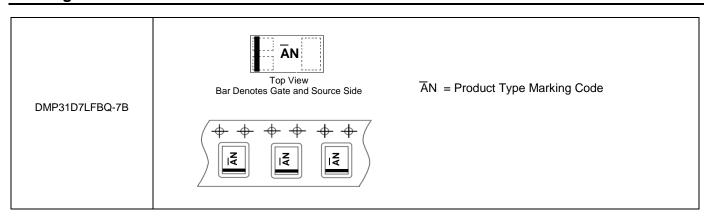
Part Number	hor Backago		Reel Size	Tape Width	Tape Pitch	Packing	
Part Number	Package	Marking (ii	(inches)	(mm)	(mm)	Qty.	Carrier
DMP31D7LFBQ-7B	X1-DFN1006-3	ĀN	7	8	2	10,000	Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3).compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information



Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage	VDSS	-30	V		
Gate-Source Voltage			V_{GSS}	±20	V
Continuous Prais Current (Note 6) Vac 10V	Steady	$T_A = +25$ °C	1-	-0.81	А
Continuous Drain Current (Note 6) V _{GS} = -10V	State	$T_A = +70$ °C	ID	-0.64	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	I _{DM}	-2.4	A		

Thermal Characteristics (@ TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	0.53	W
Thermal Resistance, Junction to Ambient (Note 5)	R _{OJA}	236	°C/W
Total Power Dissipation (Note 6)	PD	0.89	W
Thermal Resistance, Junction to Ambient (Note 6)	RөJA	141	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes:

- 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 25mm \times 25mm square copper plate.



Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

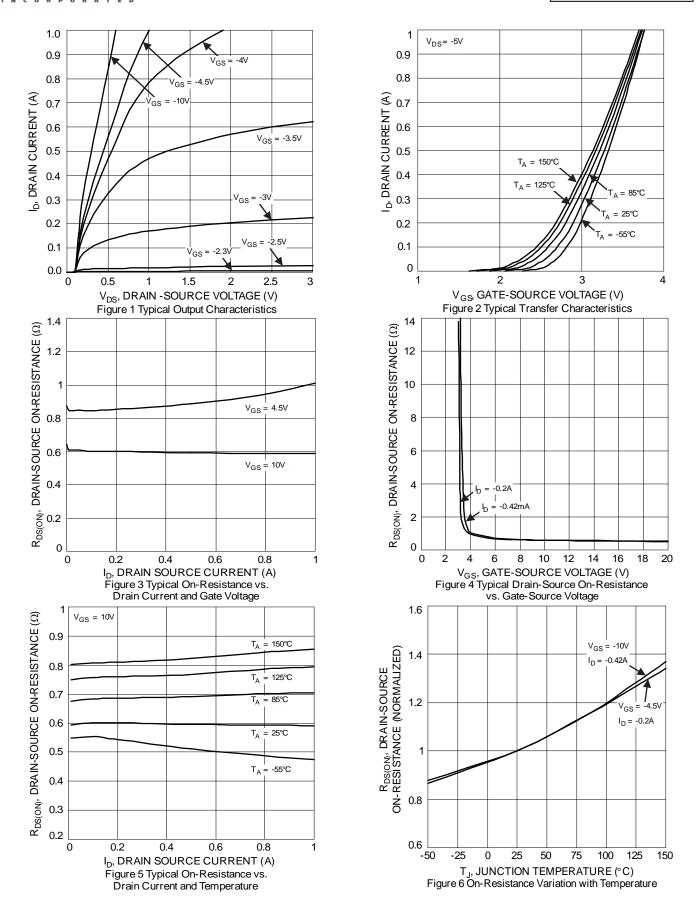
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	-30	_	_	V	$V_{GS} = 0V, I_{D} = -250\mu A$	
Zero Gate Voltage Drain Current T _J = +25°C	IDSS		1	-1	μΑ	V _{DS} = -24V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}	_	_	±10	μΑ	$V_{GS} = \pm 16V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	-1		-2.6	V	$V_{DS} = V_{GS}$, $I_{D} = -250\mu A$	
Statia Drain Source On Begintance	RDS(ON)	_	0.5	0.9	Ω	$V_{GS} = -10V, I_{D} = -0.42A$	
Static Drain-Source On-Resistance		_	0.8	1.7		$V_{GS} = -4.5V, I_{D} = -0.2A$	
Diode Forward Voltage	V _{SD}	_	-0.8	-1.2	V	$V_{GS} = 0V, I_{S} = -0.23A$	
DYNAMIC CHARACTERISTICS (Note 8)				•			
Input Capacitance	Ciss		19	_	pF		
Output Capacitance	Coss	_	16	_	pF	V _{DS} = -15V, V _{GS} = 0V, -f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	3	_	pF	1 = 1.0Wil 12	
Gate Resistance	Rg	_	729	_	Ω	$V_{DS} = V_{GS} = 0V$, $f = 1.0MHz$	
Total Gate Charge (VGS = 4.5V)	Qg	_	0.36	_	nC	15)/)/ 10)/	
Gate-Source Charge	Qgs	_	0.1	_	nC	Vgs = -4.5V, Vps = -10V,	
Gate-Drain Charge	Q_{gd}	_	0.1	_	nC	$I_D = -250 \text{mA}$	
Turn-On Delay Time	tD(ON)	_	30	_	ns		
Turn-On Rise Time	t _R	_	74	_	ns	$V_{DD} = -10V$, $V_{GS} = -4.5V$, $R_L = 47\Omega$, $R_G = 10\Omega$,	
Turn-Off Delay Time	tD(OFF)	_	28	_	ns		
Turn-Off Fall Time	tF	_	31	_	ns	I _D = -200mA	

Notes:

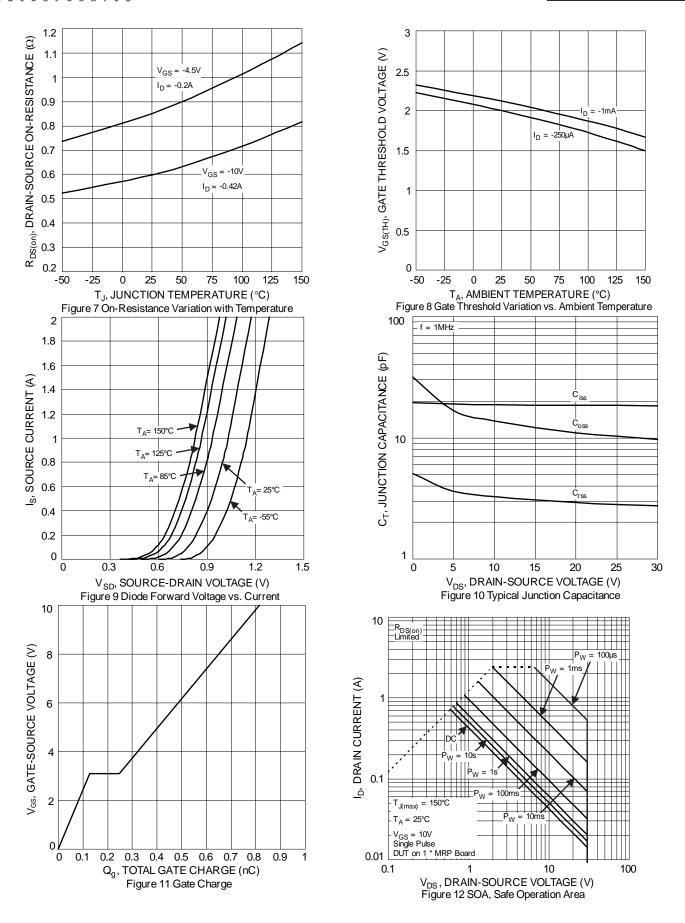
^{7.} Short duration pulse test used to minimize self-heating effect.

^{8.} Guaranteed by design. Not subject to product testing.

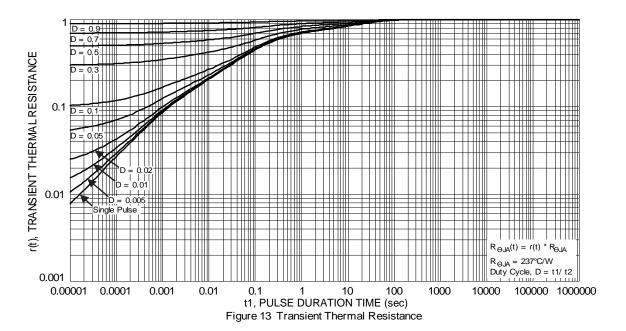










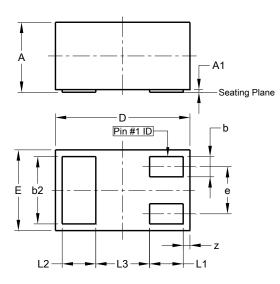




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

X1-DFN1006-3

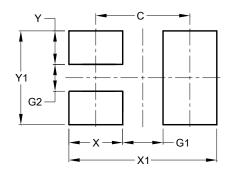


X1-DFN1006-3						
Dim	Min	Max	Тур			
Α	0.47	0.53	0.50			
A1	0.00	0.05	0.03			
b	0.10	0.20	0.15			
b2	0.45	0.55	0.50			
D	0.95	1.075	1.00			
Е	0.55	0.675	0.60			
е	ı	-	0.35			
L1	0.20	0.30	0.25			
L2	0.20	0.30	0.25			
L3	-	-	0.40			
Z	0.02	0.08	0.05			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

X1-DFN1006-3



Dimensions	Value (in mm)
С	0.70
G1	0.30
G2	0.20
Х	0.40
X1	1.10
Y	0.25
V1	0.70



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